

Orbital-Engineered Anomalous Hall Conductivity in Stable Full Heusler Compounds: A Pathway to Optimized Spintronics

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Table S1. The Anomalous Hall Conductivity ($|\sigma_{xy}|$) alongside the stability and magnetic characteristics for Co_2MnZ family. The table lists the stable phase, formation energy (ΔF in eV/atom), $|\sigma_{xy}|$ (S/Cm), total magnetic moment (M_{tot} in μ_B), spin polarization (P in %).

Co_2MnZ	Stable phase	ΔF eV/atom	$ \sigma_{xy} $ S/Cm	M_{tot} μ_B	P %
Co_2MnAl	$I2_1$	-0.385 -0.356 ^a	1647 1631 ^b , 1600-2000 ^c	4.14 4.04 ^b 4.01 ^f	63 68 ^e
Co_2MnGa	$I2_1$	-0.268 -2.237 ^a	1046 845-1260 ^d	4.09 4.11 ^b , 4.05 ^f	73 66 ^e , 55 ^g
Co_2MnB	$I2_1$	0.017 0.032 ^a	447 598 ^b , 433 ^e	4.03	82
Co_2MnIn	$I2_1$	0.024 0.064 ^a	378	4.43 4.52 ^b	27 31 ^e
Co_2MnGe	$I2_1$	-0.272 -0.257 ^a	235 253 ^b , 228 ^e	4.99 5.00 ^b , 5.11 ^f	99 100 ^e , 90 ^g
Co_2MnBi	$I2_1$	0.222 0.227 ^a	218	5.92 5.07 ^f	93
Co_2MnSn	$I2_1$	-0.132 -0.139 ^a	183 176 ^b , 174 ^e	5.00 5.04 ^b , 5.08 ^f	77 75 ^e
Co_2MnAs	$I2_1$	-0.115 -0.129 ^a	173 178 ^b	5.62 5.98 ^b 4.90 ^g	33
Co_2MnSi	$I2_1$	-0.467 -0.449 ^a	172 187 ^b , 193 ^e	5.03 5.00 ^b	1 100 ^e , 93 ^g
Co_2MnPb	$I2_1$	0.217 0.240 ^a	31	5.06	65
Co_2MnSb	$I2_1$	-0.104 -0.094 ^a	25	5.95 5.96 ^b 4.9 ^f	100

^a Theoretical data¹

^b Theoretical data²

^c Experiment data³

^d Experiment data⁴

^e Theoretical data⁵

^f Experiment data⁶

^g Experiment data⁷

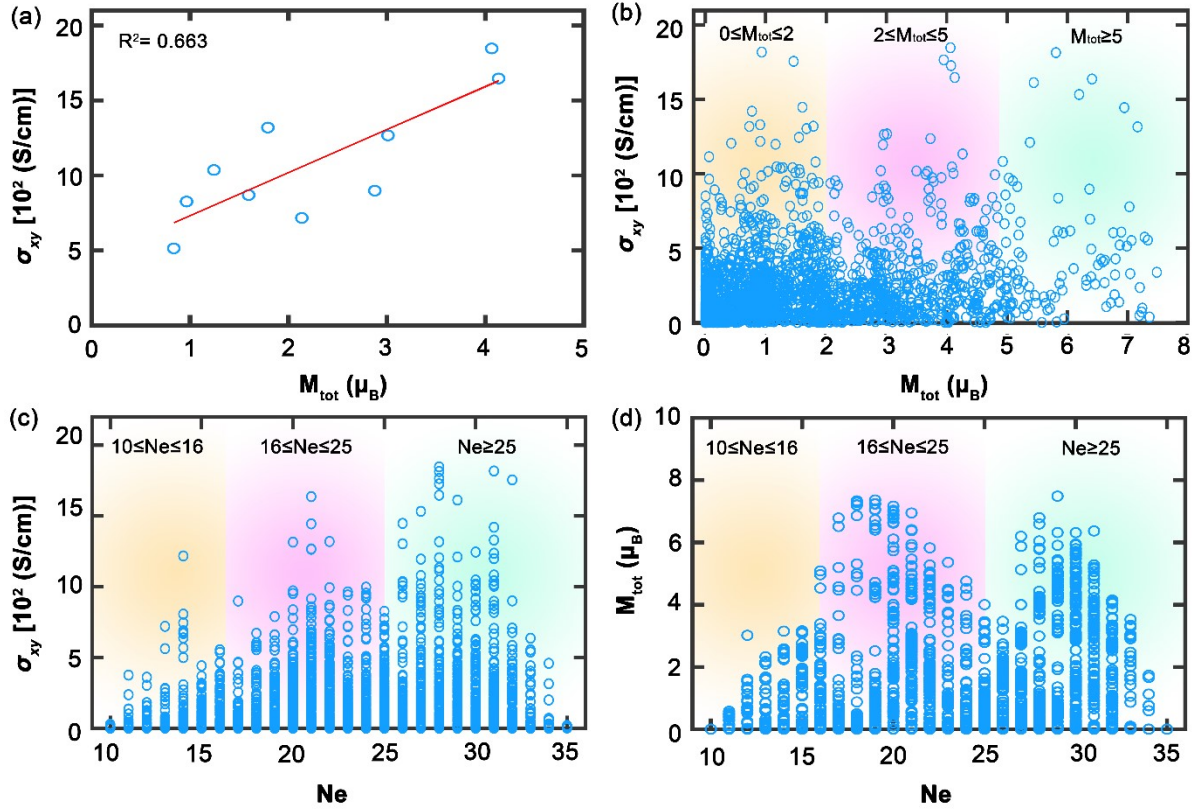


Figure S1. Anomalous Hall conductivity σ_{xy} as a function of total magnetic moment M_{tot} for data in (a) table 1 and (b) whole data. Yellow, purple, and cyan backgrounds distinguish three areas $0 \leq M_{\text{tot}} \leq 2$, $2 \leq M_{\text{tot}} \leq 5$, and $M_{\text{tot}} \geq 5$, respectively. (c) σ_{xy} and (d) M_{tot} as a function of total valence electrons Ne . Yellow, purple, and cyan backgrounds distinguish three areas $10 \leq Ne \leq 16$, $16 \leq Ne \leq 25$, and $Ne \geq 25$, respectively.

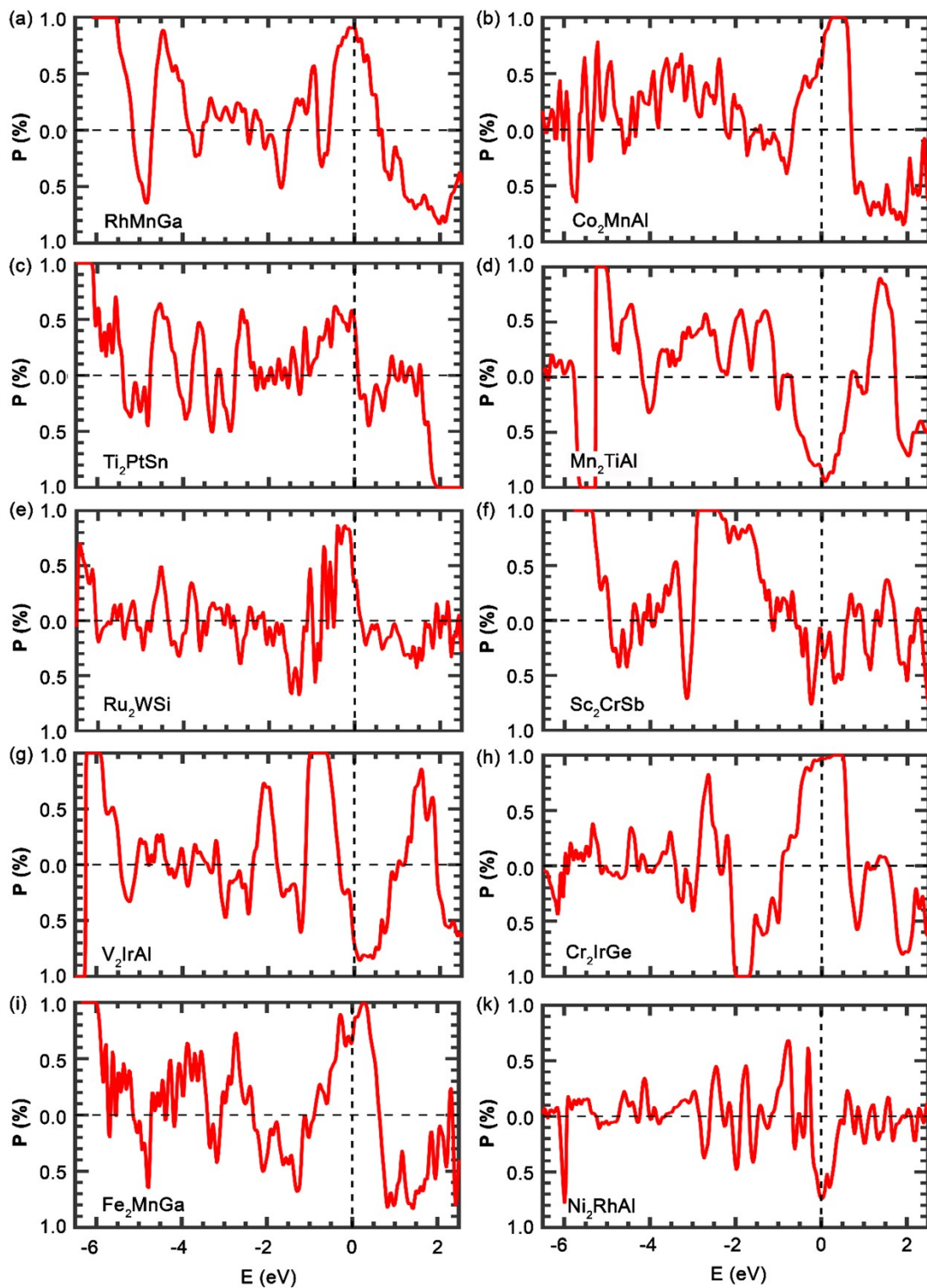


Figure S2. Spin polarization P (%) as the function of energy. for selected compounds (a) Rh_2MnGa , (b) Co_2MnAl , (c) Ti_2PtSn , (d) Mn_2TiAl , (e) Ru_2WSi , (f) Sc_2CrSb , (g) V_2IrAl , (h) Cr_2IrGe , (i) Fe_2MnGa , and (k) Ni_2RhAl . E_F is set to zero.

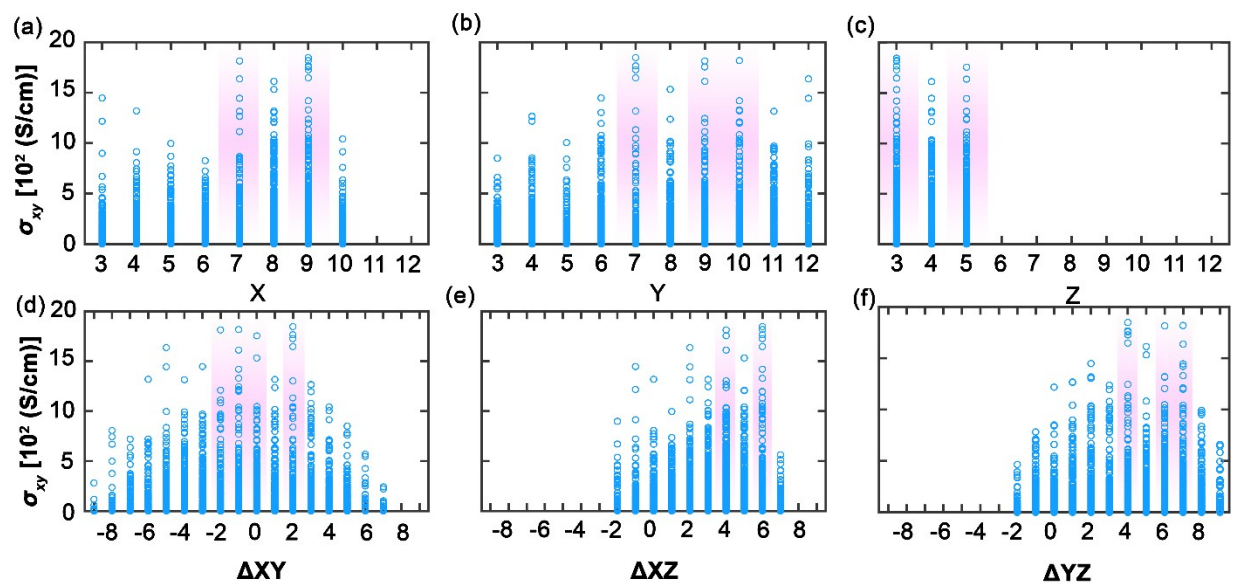


Figure S3. Anomalous Hall conductivity (σ_{xy}) as a function of valence electrons for (a) X, (b) Y, and (c) Z elements. σ_{xy} as a function of valence electron differences between (d) X and Y (ΔXY), (e) X and Z (ΔXZ), and (f) Y and Z (ΔYZ). Purple backgrounds distinguish areas exhibiting large σ_{xy} .

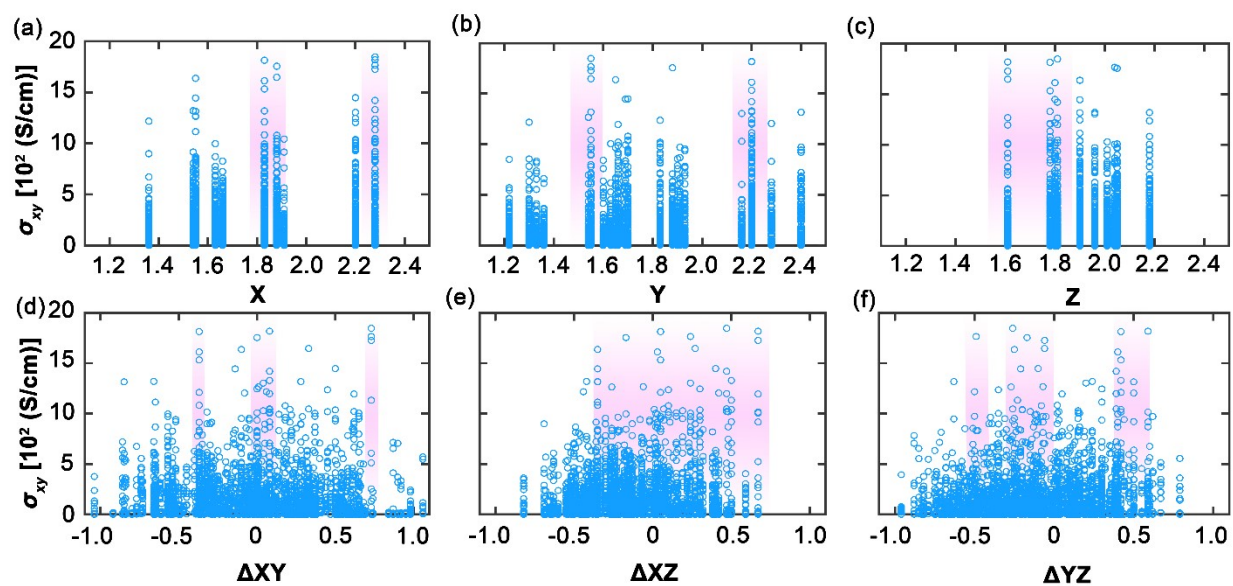


Figure S4. Anomalous Hall conductivity (σ_{xy}) as a function of electronegativity for (a) X, (b) Y, and (c) Z elements. σ_{xy} as a function of electronegativity differences between (d) X and Y (ΔXY), (e) X and Z (ΔXZ), and (f) Y and Z (ΔYZ). Purple backgrounds distinguish areas exhibiting large σ_{xy} .

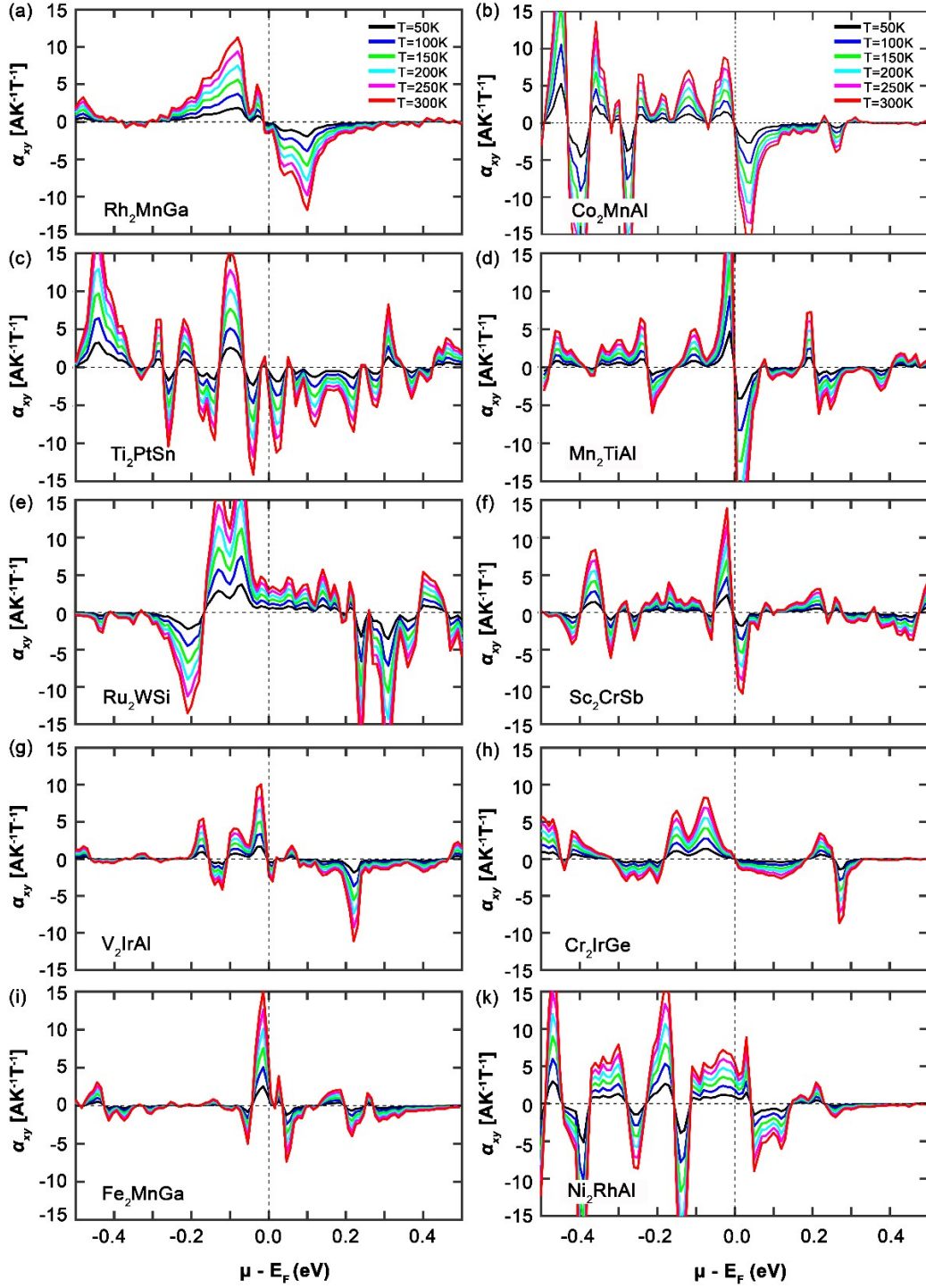


Figure S5. Anomalous Nernst conductivity (α_{xy}) as a function of chemical potential μ for selected compounds (a) Rh_2MnGa , (b) Co_2MnAl , (c) Ti_2PtSn , (d) Mn_2TiAl , (e) Ru_2WSi , (f) Sc_2CrSb , (g) V_2IrAl , (h) Cr_2IrGe , (i) Fe_2MnGa , and (k) Ni_2RhAl . E_F is set to zero.

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